



ISSN No. : 2321-9653

iJRASET

International Journal for Research in Applied
Science & Engineering Technology

iJRASET is indexed with Crossref for DOI-DOI : 10.22214

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It is here by certified that the paper ID : IJRASET48089, entitled

*Performance Analysis and Comparison of Different High-K Materials Used as Gate
Dielectrics in DH-TMSG MOSFET*

by

Anuj Gupta

*after review is found suitable and has been published in
Volume 10, Issue XII, December 2022
in*

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after review is found suitable and has been published in

Volume 10, Issue XII, December 2022

in

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